

WBC2718DT26TJ0

Top port digital silicon Microphone

Descriptions

WBC2718DT26TJ0is a Silicon Microphone with digital output and top inlet for sound input. It consists of a MEMS sensor and an encoder IC. It converts sensor analog output signal into 1-bit digital PDM data. The digital output format eliminates AC coupling capacitor, reduces RF noise coupling and eases PCB layout requirement.

WBC2718DT26TJ0 is a cost-effective alternative to traditional electret condenser microphone (ECM). Provided on tap-and-reel, it is ideally suited for high volume applications and it can be processed directly to customer's PCB using standard automatic pick-and-place equipment and surface mounted via standard solder reflow equipment.

WBC2718DT26TJ0 can be used to implement the array microphones. Speech quality can be significantly improved by combining two microphones.

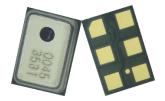
The WBC2718DT26TJ0is manufactured in a compact 2.75mm*1.85mm*0.90mm, 6-pin package.

Features

- PDM Output
- High SNR
- Multiple performance modes
- Ultra-Stable Performance
- Standard SMD Reflow
- RoHS/Halogen free compliant
- Omnidirectional

Applications

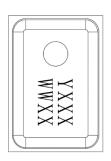
- Smart phones
- TWS/Headset
- Portable communication device
- Notebook and desktop
- Digital still cameras



Product appearance



Pin configuration (Bottom view)



Marking (Top view)

Y = Year code WW = Week code X X X = Batch code

Order information

Device	Package(mm)	Shipping
WB C2718DT26TJ0-6/TF	R 2.75*1.85*0.90	5000/Reel&Tape



Absolute Maximum Ratings

Parameter	Maximum Ratings	Unit
Power supply voltage	6.5	V
Operation temperature range	-40~85	$^{\circ}$
Storage temperature range	-40~125	$^{\circ}$

Stresses at the maximum ratings shown in Table 1 may cause permanent damage to the device. These are stress ratings only at which the device may not function when an operation at these or any other condition beyond those specified under "Electro-Acoustic Specifications".



Acoustic & Electrical Specifications

Test conditions: 23 ±2°C, 55±20% R.H., VDD=1.8V, Fclock=2.048MHz, Duty Cycle=50%, SELECT pin grounded, no load, unless otherwise indicated.

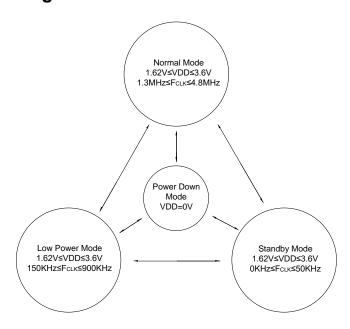
Paran	neter	Symbol	Conditions	Min	Тур	Max	Units
Supply \	Supply Voltage			1.6	-	3.6	V
		I _{DD}	Normal operation, Fclk(1.3MHz~4.8MHz)	-	770	-	uA
Supply (Current	I _{low_power}	Low power mode, Fclk(150kHz~900KHz)	1	340	-	uA
		l _{sleep}	Sleep mode, Fclk(<50KHz)	-	6	50	uA
	Sleep mode			0	-	50	KHz
Clock	Low power mode			150	-	900	KHz
Frequency Rang	Standard Performance Mode			1.3	-	4.8	MHz
Sensi	tivity	Sense	94dB SPL @1KHz	-27	-26	-25	dBFS
Signal to N	oise Ratio	SNR	Normal mode 94dB SPL @1KHz, A-weighted	-	57	-	dB(A)
Total Harmon	nic Distortion	THD	94dB SPL @1KHz, S=Typ	-	0.15	-	%
Acoustic Ove	erload Point	AOP	10%THD @1KHz, S=Typ	-	120	-	dB SPL
Power Suppl	y Rejection	PSR	100 mVpp square wave @ 217Hz, A-weighted	-	-90	-80	dBFS(A)
Power Suppl Rat		PSRR	200 mVpp sinewave @ 1 kHz	-	60	-	dBv/FS
DC Ou	utput	ZOUT	DC fullscale=±100	-	50	-	%FS
Direct	tivity			Omnidirectional			
Data F	ormat				1/2 Cycl	e 1 bit PDM	
Logic Inp	out High	Vih		0.65x V _{DD}	-	VDD+0 .3	V
Logic Inp	out Low	Vil		-0.3	-	0.35x VDD	V
Logic Out	put High	Voh		VDD- 0.45	-	-	V
Logic Out	put Low	Vol		-	-	0.45	V
Output	t Load	CLOAD		-	-	140	pF
Short Circuit O	utput Current		DATA PIN Short to GND	1		20	mA
Clock Du	ty Cycle			40		60	%
Clock Rise	/Fall Time	TEDGE		-	-	15	ns

^{1. 100%} tested.

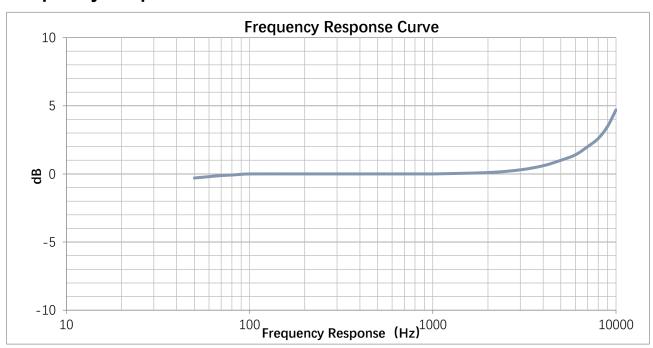


- 2. IDD varies with CLOAD according to: Δ IDD = 0.5*VDD* Δ CLOAD*FCLOCK.
- 3. Maximum specifications are measured at maximum VDD. Typical specifications are measured at standard test Conditions .
- 4. Valid microphones states are: Power Down Mode (mic off), Low Power Mode (mic clock speed), Sleep Mode (low current, DATA = high-Z, fast startup), and Normal Mode (normal operation).
- 5. Time from FCLOCK <250 kHz to ISLEEP specification is met when transitioning from Normal Mode to Sleep Mode.
- 6. Time from FCLOCK ≥ 1 MHz to all applicable specifications are met when transitioning from Sleep Mode to Normal Mode.

Microphone State Diagram

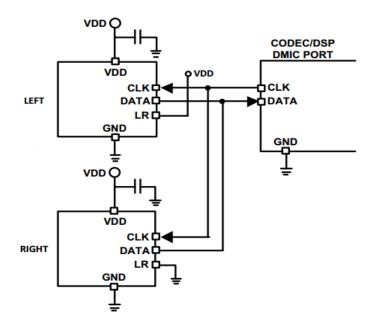


Frequency Response Curve





Application Informations



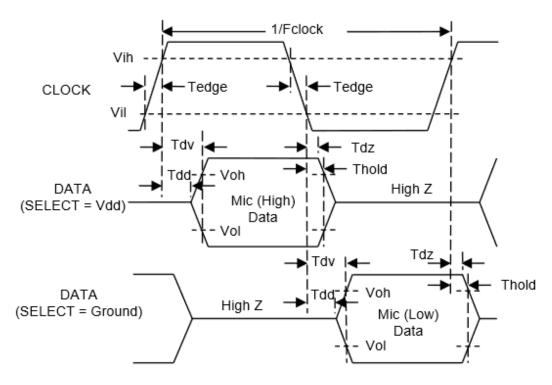
Microphone	SELECT	Asserts DATA On	Latch DATA On
Mic (High)	V_{DD}	Rising Clock Edge	Falling Clock Edge
Mic (Low)	GND	Falling Clock Edge	Rising Clock Edge

Note:

- All GND pins must be connected to ground.
- Capacitors near the microphone should not contain Class 2 dielectrics.



Clock Timing Diagram

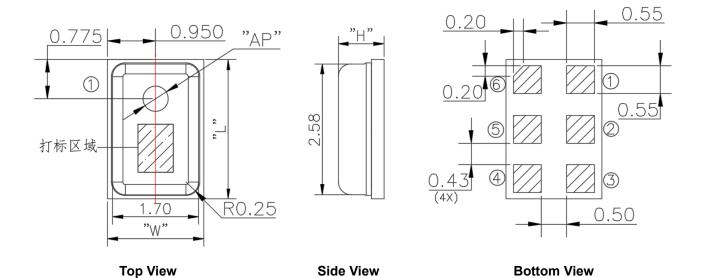


Timing Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Clock duty cycle		40	50	60	%	
Operation Voltage	V _{DD}	1.62		3.6	V	
Input Logic Low Level	VIL	-0.3		0.35×V _{DD}	V	
Input Logic High Level	V _{IH}	0.65×V _{DD}		V _{DD} +0.3	V	
Output Logic Low Level	V _{OL}			0.45	V	
Output Logic High Level	Vон	V _{DD} -0.45			V	
Clock rise time	t _{CR}			6	ns	35%~65%
Clock fall time	t _{CF}			6	ns	65%~35%
Delay time for data valid	tov	40		100	ns	Delay time from clock edge(0.50 x VDD) to data valid(<v<sub>OL or > V_{OH})</v<sub>
Delay time for data driven	too	25		50	ns	Delay time from clock edge (50% VDD) to data driven.
Delay time for data high Z	t _{Hz}	5		20	ns	Delay time from clock edge(50% VDD) to data



Mechanical Specifications



Item	Dimension	Tolerance
Length(L)	2.75	±0.10
Width(W)	1.85	±0.10
Height(H)	0.90	±0.10

Ø0.5

±0.05

Pin#	Pin Name	Description	
1	GND	GND	
2	SELECT	Lo/Hi (L/R) Select	
	2 SELECT	This pin is internally pulled low but should not be left floating	
3	GND	GND	
4	CLK Clock input		
5	DATA	DATA PDM Output	
6	VDD	Power Supply	

Notes:

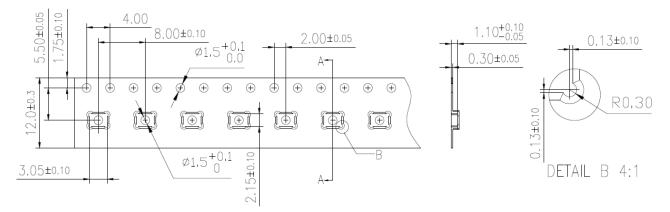
• Dimensions are in millimeters unless otherwise specified.

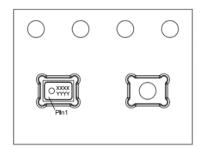
Acoustic Port (AP)

- Tolerance is ±0.10mm unless otherwise specified.
- Pick Area only extends to 0.25 mm of any edge or hole unless otherwise specified.
- Suggestion to use the same date code microphone in one array microphone module.



Packaging & Marking Detail





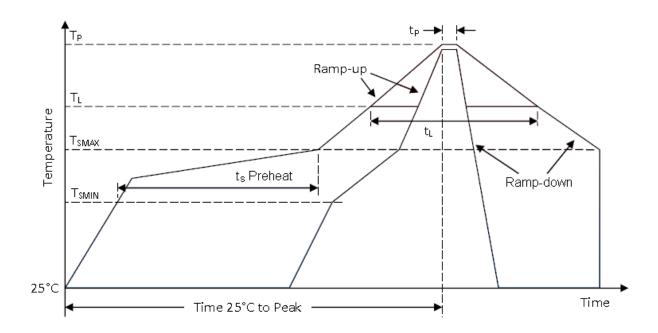
Model Number	Reel Diameter	Quantity Per Reel
WBC2718DT26TJ0	13"	5,000

Notes:

- Dimensions are in millimeters unless otherwise specified.
- Vacuum pickup only in the pick area indicated in Mechanical Specifications.
- Tape & reel per EIA-481.
- Labels applied directly to reel and external package.



Referenced Reflow Profile



Profile Feature	Pb-Free
Average Ramp-up rate (TSMAX to TP)	3°C/second max.
Preheat Temperature Min (Tsmin) Temperature Max (Tsmax) Time (Tsmin to Tsmax) (ts)	150°C 200°C 60-180 seconds
Time maintained above: • Temperature (Tւ) • Time (tւ)	217°C 60-150 seconds
Peak Temperature (T _P)	260°C
Time within 5°C of actual Peak Temperature (t _P)	20-40 seconds
Ramp-down rate (TP to TSMAX)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max

Note:

All temperatures refer to topside of the package, measured on the package body surface.



Additional Notes

- (A) Maximum of 3 reflow cycles is recommended.
- (B) In order to minimize device damage:
 - Do not board wash or clean after the reflow process.
 - Do not brush board with or without solvents after the reflow process.
 - Do not directly expose to ultrasonic processing, welding, or cleaning.
 - Do not insert any object in port hole of device at any time.
 - Do not apply over 30 psi of air pressure into the port hole.
 - Do not pull a vacuum over port hole of the microphone.
 - Do not apply a vacuum when repacking into sealed bags at a rate faster than 0.5 atm/sec.

Materials Statement

Meets the requirements of the European RoHS and Halogen-Free.

Reliability Specifications

Test	Description
Thermal Shock 100 cycles air-to-air thermal shock from -40°C to +125°C with 15 minute (IEC 68-2-4)	
High Temperature Storage	1000 hours at +105°C environment. (IEC 68-2-2 Test Ba)
Low Temperature Storage	1000 hours at -40°C environment. (IEC 68-2-2 Test Aa)
High Temperature Bias	1000 hours at +105°C under bias. (IEC 68-2-2 Test Ba)
Low Temperature Bias 1000 hours at -40°C under bias. (IEC 68-2-2 Test Aa)	
Temperature / Humidity Bias 1000 hours at +85°C /85% R.H. under bias. (JESD22-A101A-B)	
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20g peak acceleration lasting 12
	minutes in X, Y, and Z directions. (Mil-Std-883E, method 2007.2 A)
ESD-HBM 3 discharges of ±3.5kV direct contact to I/O pins. (ESD STM5.2)	
ESD-LID/GND 3 discharges of ±8 kV direct contact to lid while unit is grounded. (IEC 61	
ESD-MM 3 discharges of ±200V direct contact to I/O pins. (ESD STM5.2)	
Reflow 5 reflow cycles with peak temperature of +260°C.	
Mechanical Shock	3 pulses of 10000g in the X, Y, and Z direction. (IEC 68-2-27, Test Ea)
Drop Tost	To be no interference in operation after dropped to marble or 1.0cm steel plate
Drop Test	18 times from 1.5 meter height.

Note:

After reliability tests are performed, the sensitivity of the microphones shall not deviate more than 3 dB from its initial value. (The measurement to be done after 2 hours of conditioning at 20 \pm 2 °C, R.H 60% \sim 70%)